BUK9Y07-30B

N-channel TrenchMOS logic level FET

Rev. 03 — 7 April 2010 Product data sheet

1. Product profile

1.1 General description

Logic level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product has been designed and qualified to the appropriate AEC standard for use in automotive critical applications.

1.2 Features and benefits

- Low conduction losses due to low on-state resistance
- Q101 compliant
- Suitable for logic level gate drive sources
- Suitable for thermally demanding environments due to 175 °C rating

1.3 Applications

- 12 V loads
- Automotive systems
- General purpose power switching
- Motors, lamps and solenoids

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25$ °C; $T_j \leq 175$ °C		-	-	30	V
I_D	drain current	$V_{GS} = 5$ V; $T_{mb} = 25$ °C; see Figure 1; see Figure 4	[1]	-	-	75	A
P_{tot}	total power dissipation	$T_{mb} = 25$ °C; see Figure 2		-	-	105	W
Static characteristics							
R_{DSon}	drain-source on-state resistance	$V_{GS} = 5$ V; $I_D = 25$ A; $T_j = 25$ °C; see Figure 12; see Figure 13		-	4.9	7	mΩ
		$V_{GS} = 10$ V; $I_D = 25$ A; $T_j = 25$ °C		-	4	6	mΩ
Avalanche ruggedness							

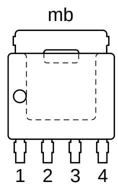
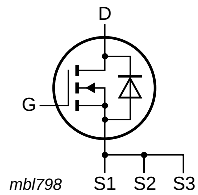
Table 1. Quick reference data *...continued*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	I_D = 75 A; V_{sup} ≤ 30 V; R_{GS} = 50 Ω; V_{GS} = 5 V; $T_{j(init)}$ = 25 °C; unclamped	-	-	198	mJ
Dynamic characteristics						
Q_{GD}	gate-drain charge	V_{GS} = 5 V; I_D = 25 A; V_{DS} = 24 V; see Figure 14	-	12.4	-	nC

[1] Continuous current is limited by package.

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		
2	S	source		
3	S	source		
4	G	gate		
mb	D	mounting base; connected to drain	SOT669 (LFPAK)	

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BUK9Y07-30B	LFPAK	plastic single-ended surface-mounted package (LFPAK); 4 leads	SOT669

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25$ °C; $T_j \leq 175$ °C		-	-	30	V
V_{DGR}	drain-gate voltage	$R_{GS} = 20$ kΩ		-	-	30	V
V_{GS}	gate-source voltage			-15	-	15	V
I_D	drain current	$T_{mb} = 25$ °C; $V_{GS} = 5$ V; see Figure 1; see Figure 4	[1]	-	-	75	A
		$T_{mb} = 100$ °C; $V_{GS} = 5$ V; see Figure 1		-	-	63	A
I_{DM}	peak drain current	$T_{mb} = 25$ °C; $t_p \leq 10$ µs; pulsed; see Figure 4		-	-	356	A
P_{tot}	total power dissipation	$T_{mb} = 25$ °C; see Figure 2		-	-	105	W
T_{stg}	storage temperature			-55	-	175	°C
T_j	junction temperature			-55	-	175	°C
Source-drain diode							
I_S	source current	$T_{mb} = 25$ °C	[1]	-	-	75	A
I_{SM}	peak source current	$t_p \leq 10$ µs; pulsed; $T_{mb} = 25$ °C		-	-	356	A
Avalanche ruggedness							
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 75$ A; $V_{sup} \leq 30$ V; $R_{GS} = 50$ Ω; $V_{GS} = 5$ V; $T_{j(init)} = 25$ °C; unclamped		-	-	198	mJ
$E_{DS(AL)R}$	repetitive drain-source avalanche energy	see Figure 3	[2][3][4][5]	-	-	-	J

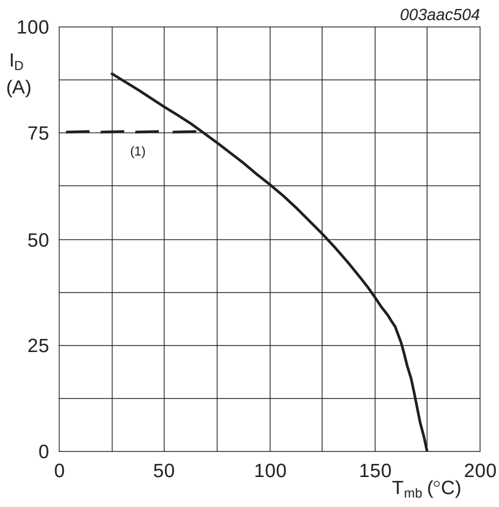
[1] Continuous current is limited by package.

[2] Maximum value not quoted. Repetitive rating defined in avalanche rating figure.

[3] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[4] Repetitive avalanche rating limited by an average junction temperature of 170 °C.

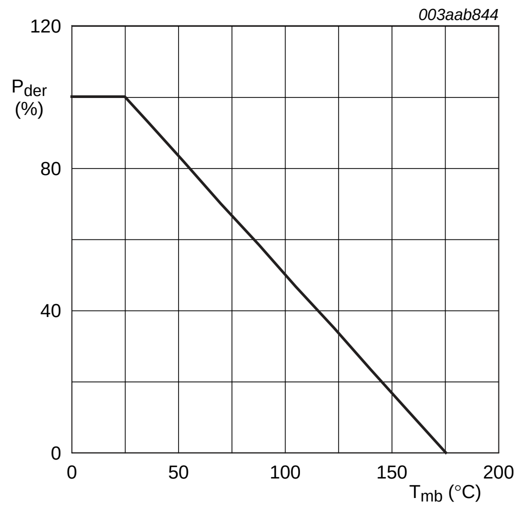
[5] Refer to application note AN10273 for further information.



$V_{GS} \geq 10 V$

(1) Capped at 75 A due to package.

Fig 1. Continuous drain current as a function of mounting base temperature



$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ C)}} \times 100\,\%$$

Fig 2. Normalized total power dissipation as a function of mounting base temperature

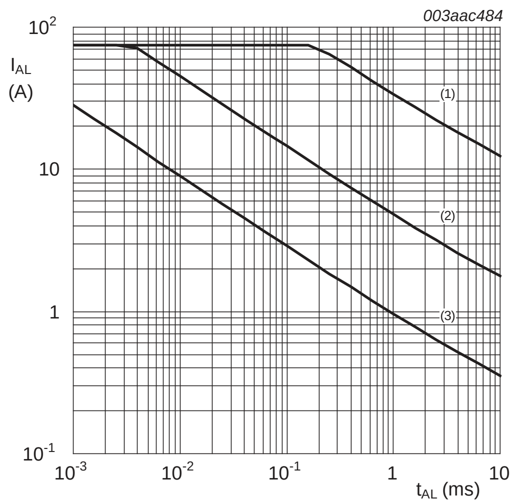
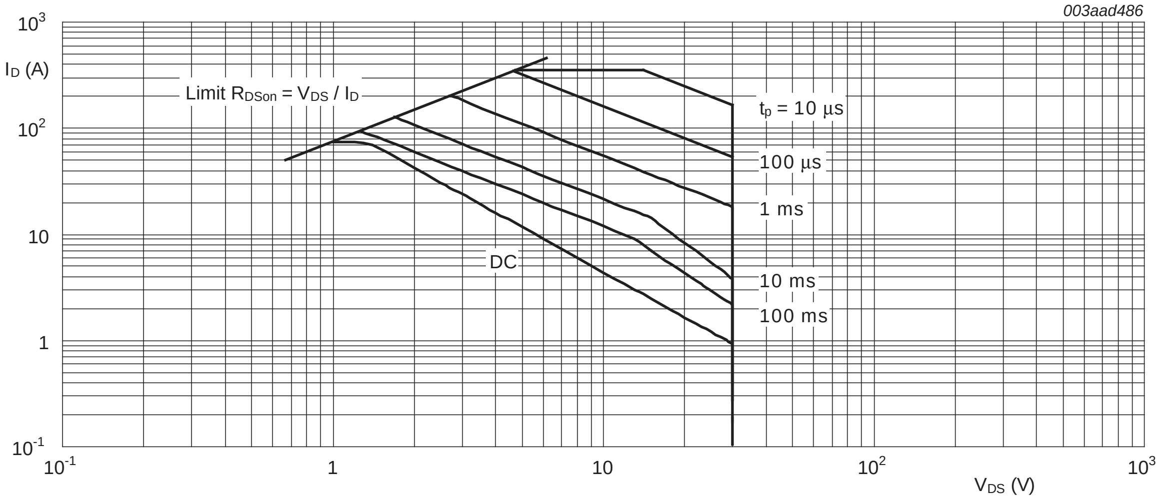


Fig 3. Single-pulse and repetitive avalanche rating; avalanche current as a function of avalanche time



$T_{mb} = 25\,°C; I_{DM}$ is single pulse

Fig 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see Figure 5	-	-	1.42	K/W

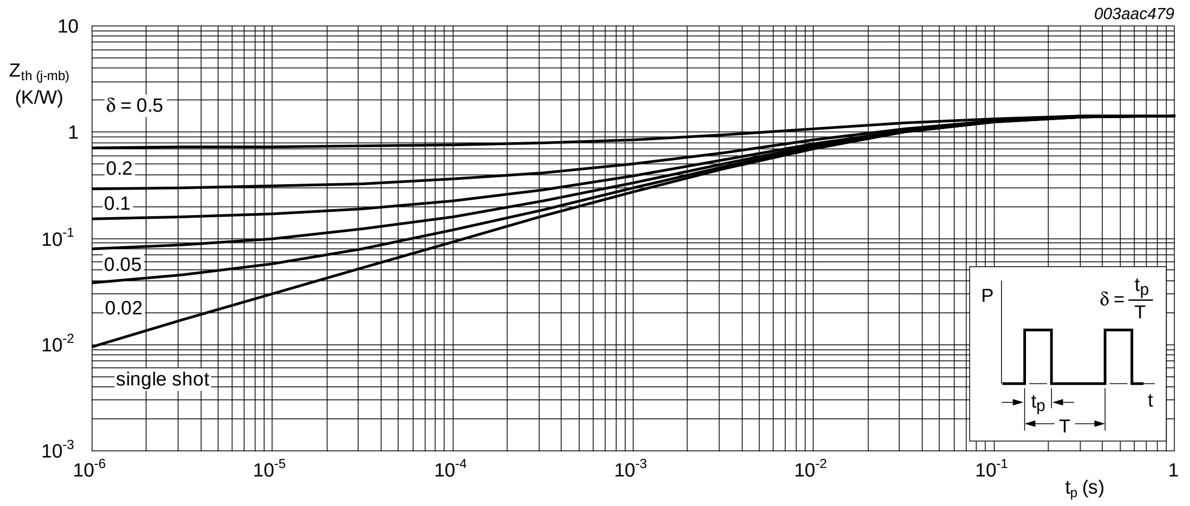
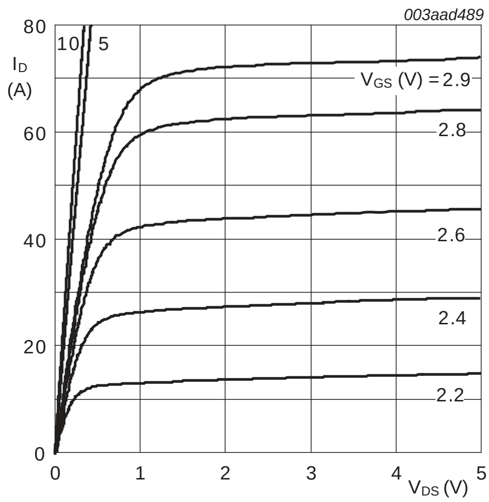


Fig 5. Transient thermal impedance from junction to mounting base as a function of pulse duration.

6. Characteristics

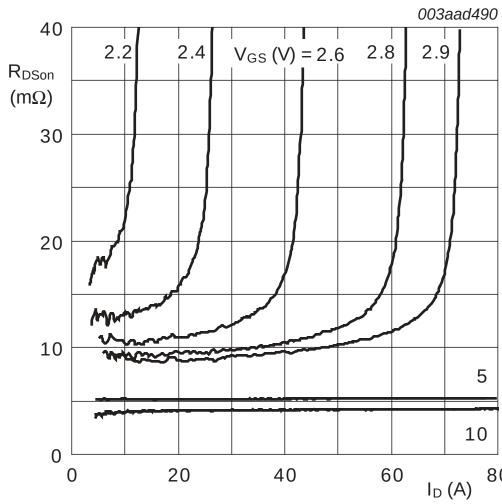
Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	I_D = 0.25 mA; V_{GS} = 0 V; T_j = -55 °C	27	-	-	V
		I_D = 0.25 mA; V_{GS} = 0 V; T_j = 25 °C	30	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25 °C; see Figure 10; see Figure 11	1.1	1.5	2	V
V_{GSth}	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS}; T_j = 175 °C; see Figure 10; see Figure 11	0.5	-	-	V
		I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55 °C; see Figure 10; see Figure 11	-	-	2.3	V
I_{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C	-	0.02	1	µA
		V_{DS} = 30 V; V_{GS} = 0 V; T_j = 175 °C	-	-	500	µA
I_{GSS}	gate leakage current	V_{DS} = 0 V; V_{GS} = 15 V; T_j = 25 °C	-	2	100	nA
		V_{DS} = 0 V; V_{GS} = -15 V; T_j = 25 °C	-	2	100	nA
R_{DSon}	drain-source on-state resistance	V_{GS} = 5 V; I_D = 25 A; T_j = 25 °C; see Figure 12; see Figure 13	-	4.9	7	mΩ
		V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C	-	-	8	mΩ
		V_{GS} = 5 V; I_D = 25 A; T_j = 175 °C; see Figure 12; see Figure 13	-	-	13.3	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C	-	4	6	mΩ
Dynamic characteristics						
$Q_{G(tot)}$	total gate charge	I_D = 25 A; V_{DS} = 24 V; V_{GS} = 5 V; see Figure 14	-	28.1	-	nC
Q_{GS}	gate-source charge		-	6.7	-	nC
Q_{GD}	gate-drain charge		-	12.4	-	nC
C_{iss}	input capacitance	V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz; T_j = 25 °C; see Figure 15	-	1580	2500	pF
C_{oss}	output capacitance		-	500	600	pF
C_{rss}	reverse transfer capacitance		-	225	308	pF
$t_{d(on)}$	turn-on delay time	V_{DS} = 25 V; R_L = 1 Ω; V_{GS} = 5 V; $R_{G(ext)}$ = 10 Ω	-	25.9	-	ns
t_r	rise time		-	64.5	-	ns
$t_{d(off)}$	turn-off delay time		-	82.3	-	ns
t_f	fall time		-	64.8	-	ns
Source-drain diode						
V_{SD}	source-drain voltage	I_S = 25 A; V_{GS} = 0 V; T_j = 25 °C; see Figure 16	-	0.85	1.2	V
t_{rr}	reverse recovery time	I_S = 20 A; dI_S/dt = -100 A/µs; V_{GS} = 0 V; V_{DS} = 30 V	-	39.3	-	ns
Q_r	recovered charge		-	53.7	-	nC



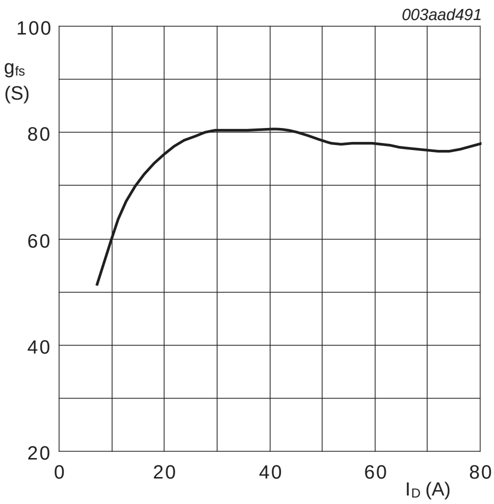
$T_j = 25\,°C$

Fig 6. Output characteristics: drain current as a function of drain-source voltage; typical values.



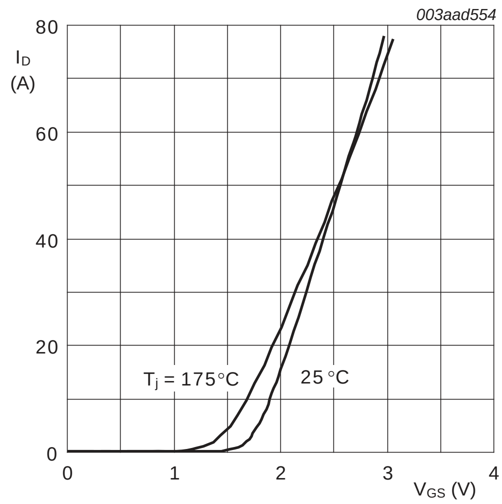
$T_j = 25\,°C$

Fig 7. Drain-source on-state resistance as a function of drain current; typical values.



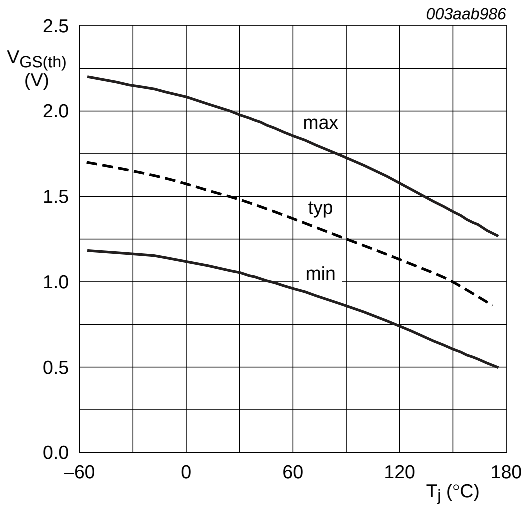
$T_j = 25\,°C; V_{DS} = 25\,V$

Fig 8. Forward transconductance as a function of drain current; typical values.



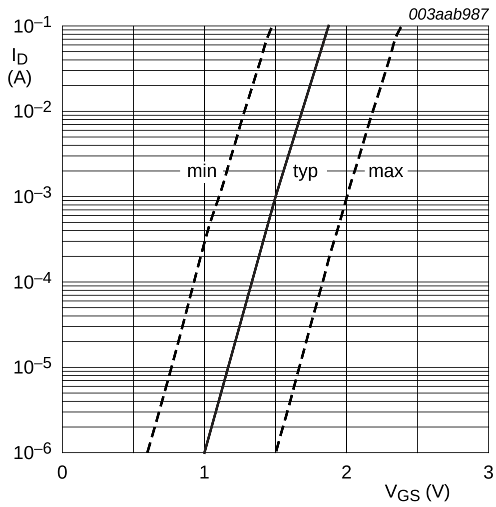
$V_{DS} = 25\,V$

Fig 9. Transfer characteristics: drain current as a function of gate-source voltage; typical values.



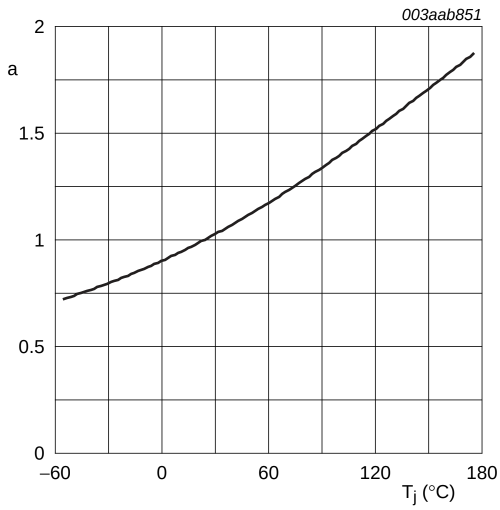
$I_D = 1mA; V_{DS} = V_{GS}$

Fig 10. Gate-source threshold voltage as a function of junction temperature



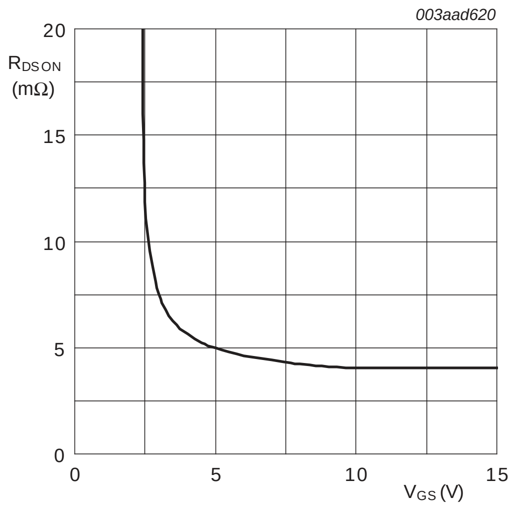
$T_j = 25\,°C; V_{DS} = V_{GS}$

Fig 11. Sub-threshold drain current as a function of gate-source voltage



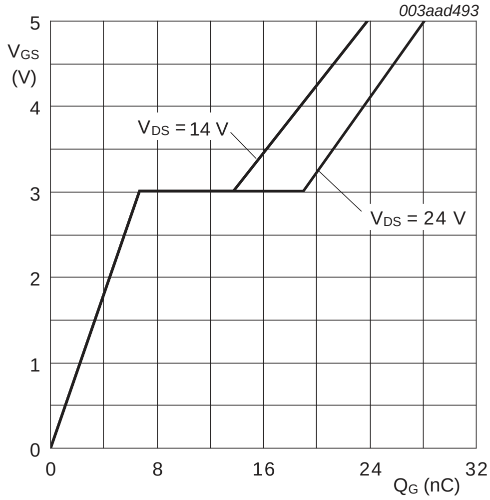
$$a = \frac{R_{DSon}}{R_{DSon(25°C)}}$$

Fig 12. Normalized drain-source on-state resistance factor as a function of junction temperature



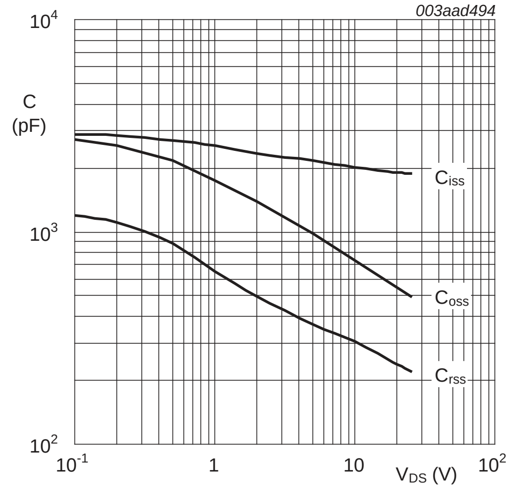
$T_j = 25\,°C; I_D = 25A$

Fig 13. Drain-source on-state resistance as a function of gate-source voltage; typical values.



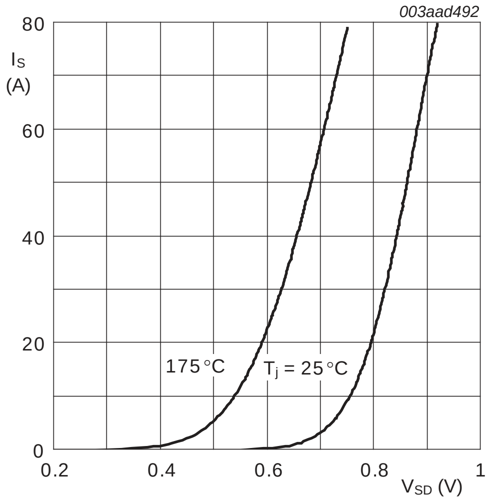
$T_j = 25\,°C; I_D = 25A$

Fig 14. Gate-source voltage as a function of gate charge; typical values.



$V_{GS} = 0V; f = 1MHz$

Fig 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values.

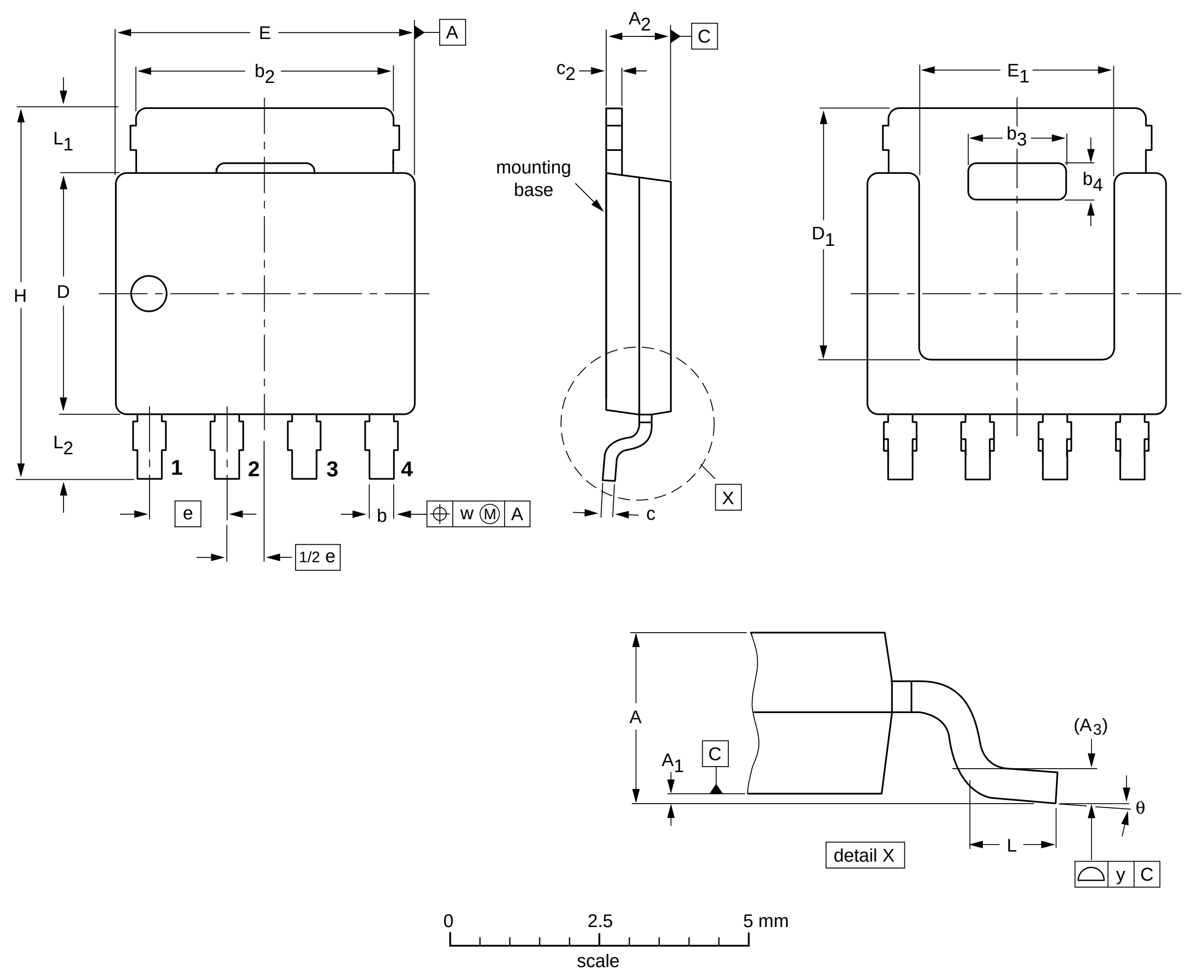


$V_{GS} = 0V$

Fig 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values.

7. Package outline

Plastic single-ended surface-mounted package (LFPAK); 4 leads **SOT669**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	A_2	A_3	b	b_2	b_3	b_4	c	c_2	D(1)	D_1(1) max	E(1)	E_1(1)	e	H	L	L_1	L_2	w	y	θ
mm	1.20 1.01	0.15 0.00	1.10 0.95	0.25	0.50 0.35	4.41 3.62	2.2 2.0	0.9 0.7	0.25 0.19	0.30 0.24	4.10 3.80	4.20	5.0 4.8	3.3 3.1	1.27	6.2 5.8	0.85 0.40	1.3 0.8	1.3 0.8	0.25	0.1	8° 0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT669		MO-235				~~04-10-13~~ 06-03-16

Fig 17. Package outline SOT669 (LFPAK)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BUK9Y07-30B_3	20100407	Product data sheet	-	BUK9Y07-30B_2
Modifications:	• Status changed from objective to product.			
BUK9Y07-30B_2	20100215	Objective data sheet	-	BUK9Y07-30B_1

9. Legal information

9.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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